

Suppose a step function voltage V_A was suddenly applied across the anchors of a $2\ \mu\text{m}$ thick polysilicon beam and proof mass setup as shown in Figures PS1.3-1 and PS1.3-2, which also provide lateral dimensions. For polysilicon, assume the following material properties: Young's modulus $E = 150\ \text{GPa}$, density $\rho = 2300\ \text{kg/m}^3$, Poisson ratio $\nu = 0.226$, sheet resistance (resistivity \cdot thickness $^{-1}$) = $10\ \Omega/\square$, specific heat = $0.77\ \text{J}/(\text{g}\cdot\text{K})$, and thermal conductivity = $30\ \text{W}/(\text{m}\cdot\text{K})$.

- (a) With what time constant will the proof mass reach its steady-state temperature after the voltage V_A steps from 0V to 1V ? Give a formula and a numerical answer with units.
- (b) If the final step function value of V_A is 1V , what is the steady-state temperature of the proof mass? Give a formula and a numerical answer with units.
- (c) What effect do you think the applied voltage has on the resonance frequency of the structure in the z -direction (into the page)? Give a brief qualitative explanation.

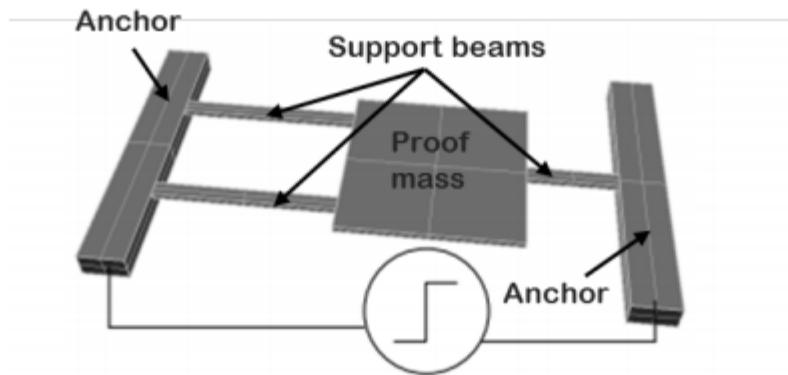


Figure PS1.3-1

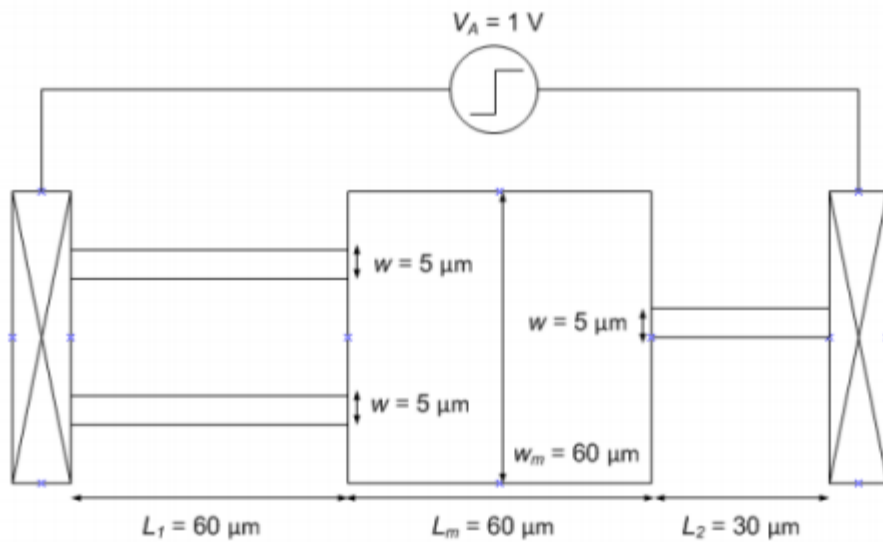
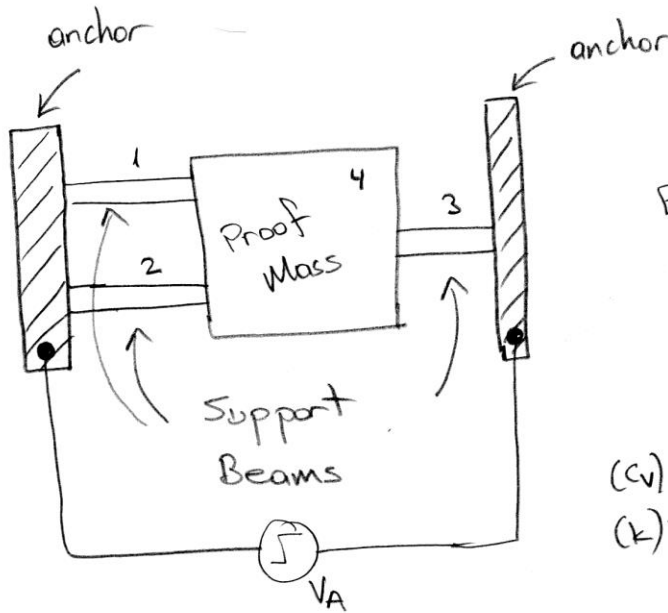


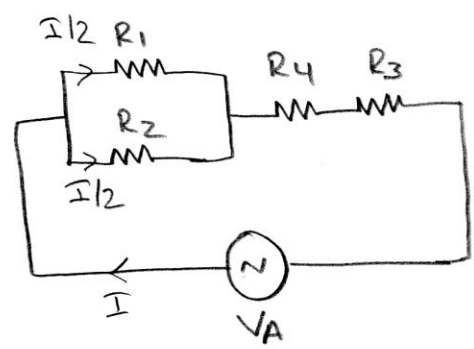
Figure PS1.3-2



Polysilicon (2μm thick)

- $E = 150 \text{ GPa}$
- $\rho = 2300 \text{ kg/m}^3$
- $\nu = 0.226$
- Sheet Res. = $10 \Omega/\square$
- (cv) Spec. Heat = $0.77 \text{ J/g}\cdot\text{K}$
- (k) Thermal cond = $30 \text{ W/m}\cdot\text{K}$

① Find the electrical circuit:



$R_1 = 12 (10 \Omega/\square) = 120 \Omega$
 $R_2 = 120 \Omega$
 $R_3 = 60 \Omega$
 $R_4 = 10 \Omega$

$$I = \frac{VA}{R_1 \parallel R_2 + R_3 + R_4} = \frac{1V}{130 \Omega} = 7.7 \text{ mA}$$

Powers:
 $P_1 = \left(\frac{I}{2}\right)^2 R_1 = 1.78 \text{ mW}$, $P_2 = \left(\frac{I}{2}\right)^2 R_2 = 1.78 \text{ mW}$, $P_3 = I^2 R_3 = 3.56 \text{ mW}$, $P_4 = 0.59 \text{ mW}$

* $P_1 - P_4$ will be power inputs to the thermal circuit.

② Find the thermal circuit:

$$R_{th1} = \frac{l}{kA} = \frac{60 \mu}{(30)(2 \mu)(5 \mu)} = 0.2 \text{ MK/W}$$

$$C_{th1} = \rho C_v V = (2300)(770)(2 \mu \cdot 5 \mu \cdot 60 \mu) = 1.06 \text{ nJ/K}$$

$$R_{th2} = R_{th1} = 0.2 \text{ MK/W}$$

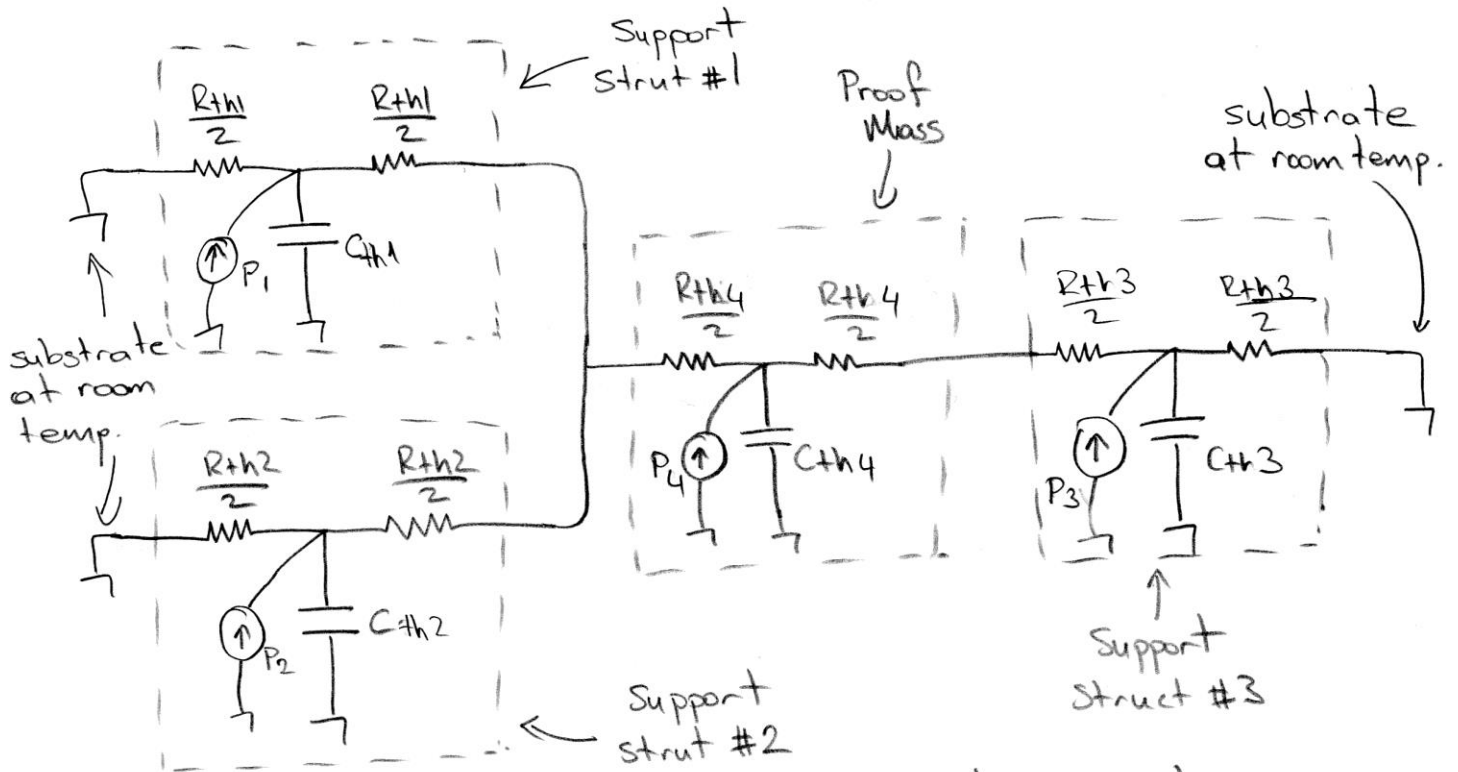
$$C_{th2} = C_{th1} = 1.06 \text{ nJ/K}$$

$$R_{th3} = 0.1 \text{ MK/W}$$

$$C_{th3} = 0.53 \text{ nJ/K}$$

$$R_{th4} = \frac{60 \mu}{(30)(60 \mu)(2 \mu)} = 16 \text{ kK/W}$$

$$C_{th4} = 12.75 \text{ nJ/K}$$



③ Simplify the thermal circuit w/ appropriate assumptions:

$C_{th1} = 1.06 \text{ nJ/K}$
 $C_{th2} = 1.06 \text{ nJ/K}$
 $C_{th3} = 0.53 \text{ nJ/K}$
 $C_{th4} = 12.75 \text{ nJ/K}$

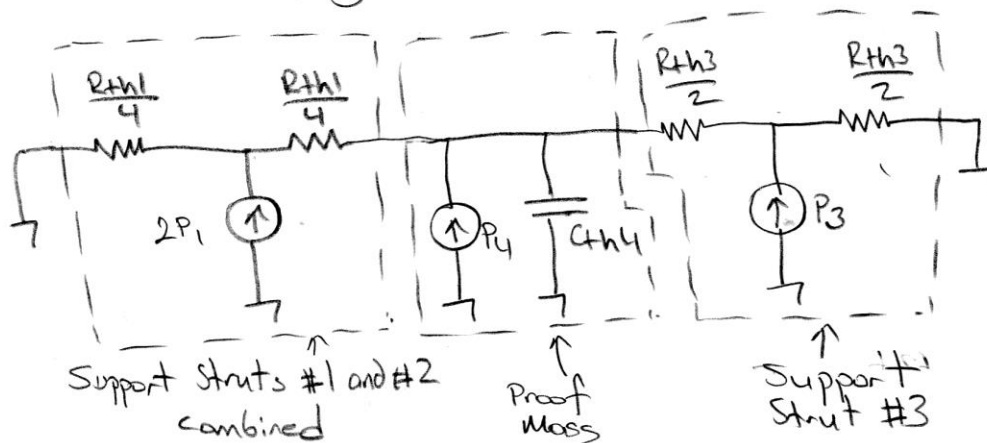
$C_{th1} \ll C_{th4}$
 $C_{th2} \ll C_{th4}$
 $C_{th3} \ll C_{th4}$

$R_{th1} = 200 \text{ kK/W}$
 $R_{th2} = 200 \text{ kK/W}$
 $R_{th3} = 100 \text{ kK/W}$
 $R_{th4} = 16 \text{ kK/W}$

$R_{th4} \ll R_{th1}$
 $R_{th4} \ll R_{th2}$
 $R_{th4} \ll R_{th3}$

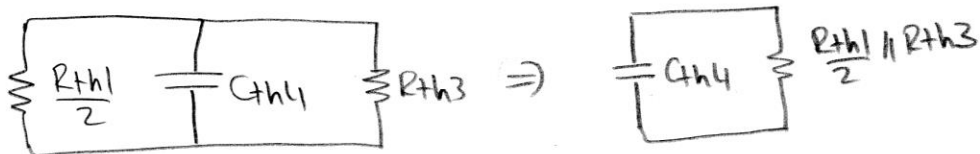
neglect $C_{th1}, C_{th2}, C_{th3}$

neglect R_{th4}



Simplified steady-state circuit

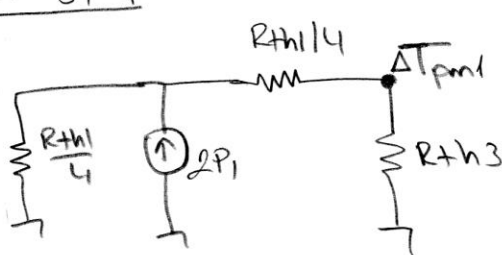
(a) Time constant circuit: kill all independent sources, i.e. short circuit voltage sources and open-circuit current sources:



$$\tau = \left(\frac{R_{th1}}{2} \parallel R_{th3} \right) C_{th4} = 0.6375 \text{ ms} \\ = 637.5 \mu\text{s}$$

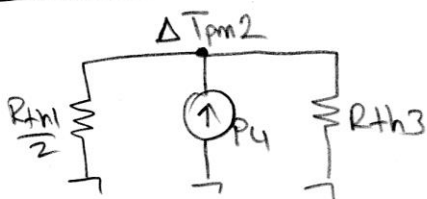
(b) Apply superposition: (at steady-state all capacitors are fully-charged/open)

① Kill P_3, P_4 :



$$\Delta T_{pm1} = 2P_1 \frac{\frac{R_{th1}}{4}}{\frac{R_{th1}}{2} + R_{th3}} \quad R_{th3} = 89 \text{ K}$$

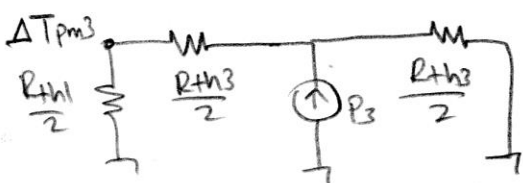
② Kill $2P_1, P_3$:



$$\Delta T_{pm2} = \left(R_{th3} \parallel \frac{R_{th1}}{2} \right) P_4 = 29.5 \text{ K}$$

↑ even P_4 could be neglected!

③ Kill $2P_1, P_4$:



$$\Delta T_{pm3} = P_3 \frac{\frac{R_{th3}}{2}}{R_{th3} + \frac{R_{th1}}{2}} \quad \frac{R_{th1}}{2} = 89 \text{ K}$$

room temp.

$$\text{In total} \Rightarrow T_{pm} = T_0 + \sum_{i=1}^3 \Delta T_{pmi} = 298 \text{ K} + 89 \text{ K} + 29.5 \text{ K} + 89 \text{ K} = 505.5 \text{ K}$$

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DISCUSSION #3

218/2016
EE247B/ME218

* What happens if we neglect P_4 ?

$$T_{pm}' = 298K + 89K + 89K = 476K$$

$$\text{err} = 100 \left(\frac{T_{pm} - T_{pm}'}{T_{pm}} \right) = \left(1 - \frac{T_{pm}'}{T_{pm}} \right) 100 = \underbrace{5.84\%}_{\text{so you're still fine!}} < 10\%$$

(c) Joule heating causes polysilicon to expand but since the anchors are fixed, compressive axial stress results in the beams. This lowers the beam stiffness and thus lowers the resonance frequency $\downarrow \omega_0 = \sqrt{\frac{k}{m}}$